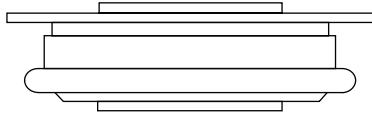


Fast Recovery Diodes (Hockey PUK Version), 430 A



DO-200AA

FEATURES

- High power FAST recovery diode series
- 1.0 to 1.5 μ s recovery time
- High voltage ratings up to 1600 V
- High current capability
- Optimized turn-on and turn-off characteristics
- Low forward recovery
- Fast and soft reverse recovery
- Press PUK encapsulation
- Case style conform to JEDEC DO-200AA
- Maximum junction temperature 125 °C
- Lead (Pb)-free


RoHS
COMPLIANT

PRODUCT SUMMARY

$I_{F(AV)}$	430 A
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TYPICAL APPLICATIONS

- Snubber diode for GTO
- High voltage freewheeling diode
- Fast recovery rectifier applications

MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		430	A
	T_{hs}	55	°C
$I_{F(RMS)}$		675	A
	T_{hs}	25	°C
I_{FSM}	50 Hz	6180	A
	60 Hz	6470	
I^2t	50 Hz	191	kA ² s
	60 Hz	175	
V_{RRM}	Range	400 to 1600	V
t_{rr}		1.0 to 1.5	μ s
	T_J	25	°C
T_J		- 40 to 125	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 125 °C mA
SD403C..S10C	04	400	500	35
	08	800	900	
	10	1000	1100	
SD403C..S15C	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

FORWARD CONDUCTION					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current at heatsink temperature	I _{F(AV)}	180° conduction, half sine wave Double side (single side) cooled		430 (210)	A
				55 (75)	°C
Maximum RMS current	I _{F(RMS)}	25 °C heatsink temperature double side cooled		675	A
Maximum peak, one-cycle, non-repetitive forward current	I _{FSM}	t = 10 ms	No voltage reappplied	6180	
		t = 8.3 ms		6470	
		t = 10 ms	100 % V _{RRM} reappplied	5200	
		t = 8.3 ms		5445	
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reappplied	191	
		t = 8.3 ms		175	
		t = 10 ms	100 % V _{RRM} reappplied	135	
		t = 8.3 ms		123	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reappplied		1910	kA ² √s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % × π × I _{F(AV)} < I < π × I _{F(AV)}), T _J = T _J maximum		1.00	V
High level value of threshold voltage	V _{F(TO)2}	(I > π × I _{F(AV)}), T _J = T _J maximum		1.20	
Low level of forward slope resistance	r _{f1}	(16.7 % × π × I _{F(AV)} < I < π × I _{F(AV)}), T _J = T _J maximum		0.56	mΩ
High level of forward slope resistance	r _{f2}	(I > π × I _{F(AV)}), T _J = T _J maximum		0.70	
Maximum forward voltage drop	V _{FM}	I _{pk} = 1350 A, T _J = 25 °C; t _p = 10 ms sinusoidal wave		1.83	V

RECOVERY CHARACTERISTICS								
CODE	MAXIMUM VALUE AT T _J = 25 °C	TEST CONDITIONS			TYPICAL VALUES AT T _J = 125 °C			
	t _{rr} AT 25 % I _{RRM} (μs)	I _{pk} SQUARE PULSE (A)	di/dt (A/μs)	V _r (V)	t _{rr} AT 25 % I _{RRM} (μs)	Q _{rr} (μC)	I _{rr} (A)	
S10	1.0	750	25	- 30	2.4	52	33	
S15	1.5				2.9	90	44	



THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum operating temperature range	T_J		- 40 to 125	°C
Maximum storage temperature range	T_{Stg}		- 40 to 150	
Maximum thermal resistance, junction to heatsink	R_{thJ-hs}	DC operation single side cooled	0.16	K/W
		DC operation double side cooled	0.08	
Mounting force, $\pm 10\%$			4900 (500)	N (kg)
Approximate weight			70	g
Case style		See dimensions - link at the end of datasheet	DO-200AA	

ΔR_{thJ-hs} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS
	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE		
180°	0.010	0.011	0.008	0.008	$T_J = T_J$ maximum	K/W
120°	0.012	0.013	0.013	0.013		
90°	0.016	0.016	0.018	0.018		
60°	0.024	0.024	0.025	0.025		
30°	0.042	0.042	0.042	0.042		

Note

- The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

SD403C..C Series



Vishay High Power Products Fast Recovery Diodes
(Hockey PUK Version), 430 A

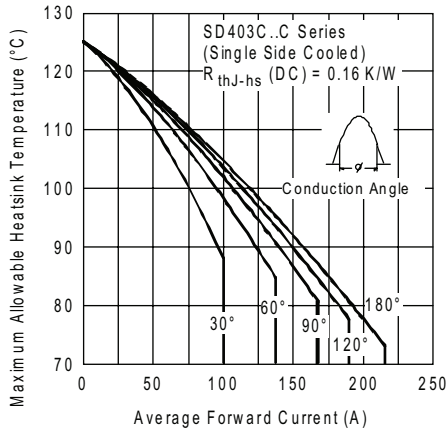


Fig. 1 - Current Ratings Characteristics

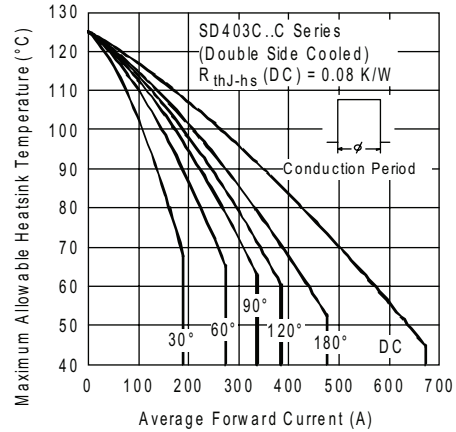


Fig. 4 - Current Ratings Characteristics

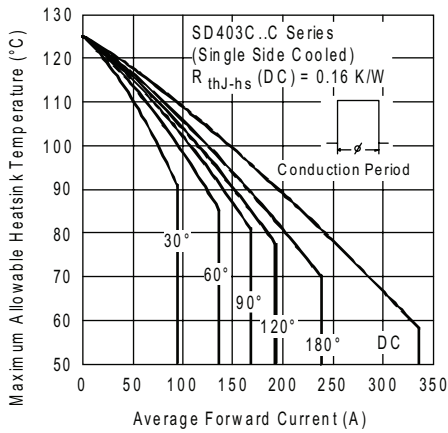


Fig. 2 - Current Ratings Characteristics

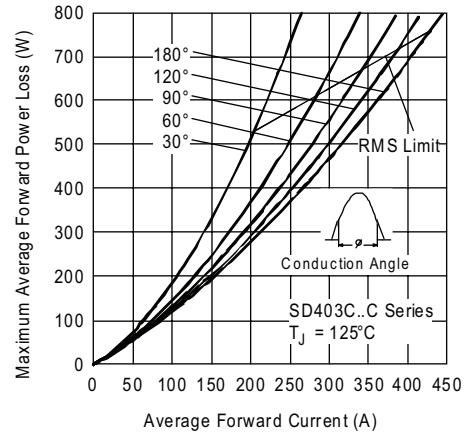


Fig. 5 - Forward Power Loss Characteristics

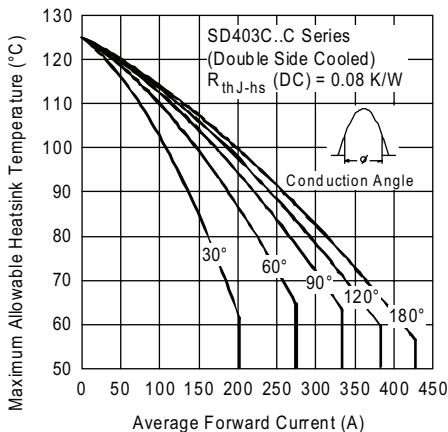


Fig. 3 - Current Ratings Characteristics

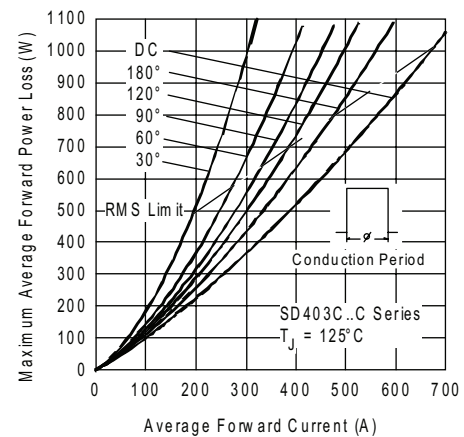


Fig. 6 - Forward Power Loss Characteristics

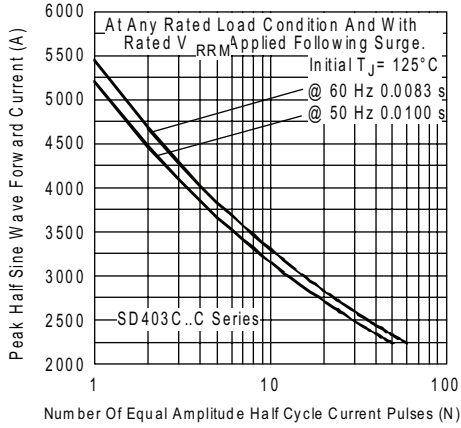


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

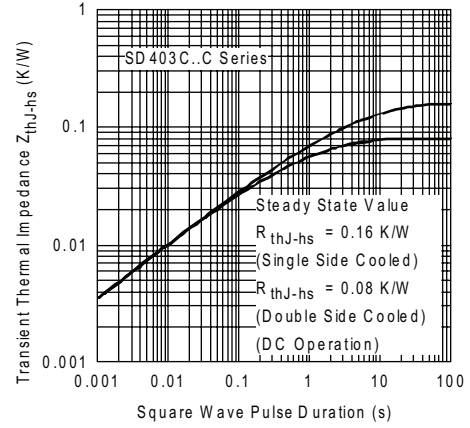


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

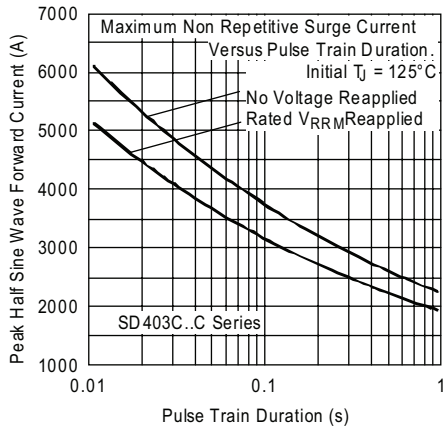


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

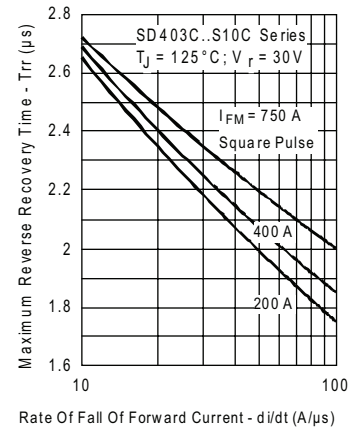


Fig. 11 - Recovery Time Characteristics

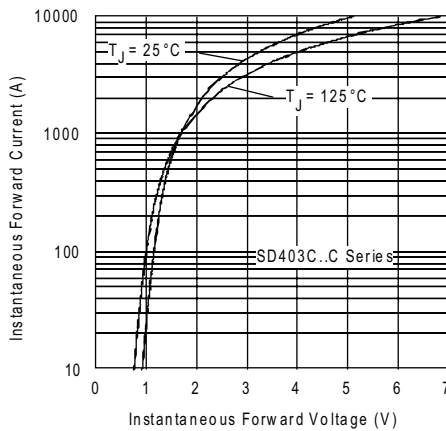


Fig. 9 - Forward Voltage Drop Characteristics

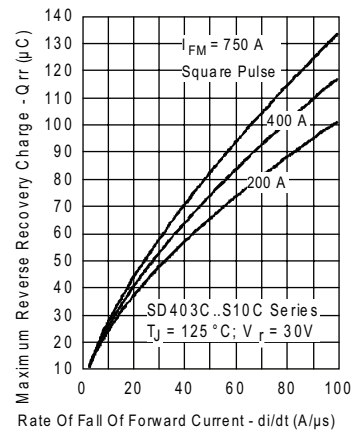


Fig. 12 - Recovery Charge Characteristics

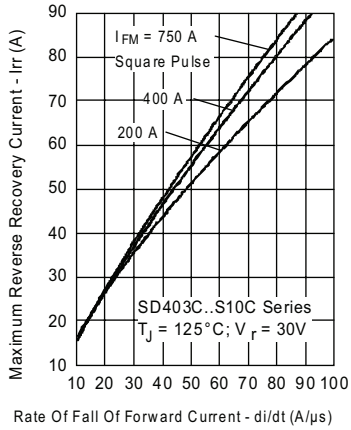


Fig. 13 - Recovery Current Characteristics

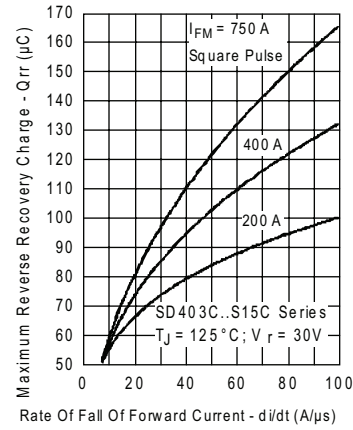


Fig. 15 - Recovery Charge Characteristics

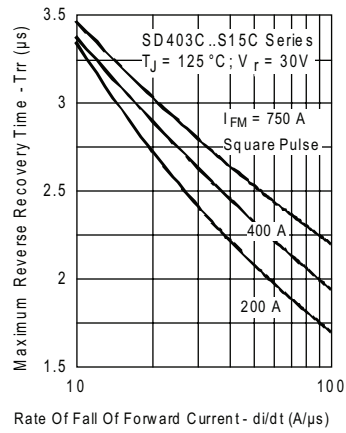


Fig. 14 - Recovery Time Characteristics

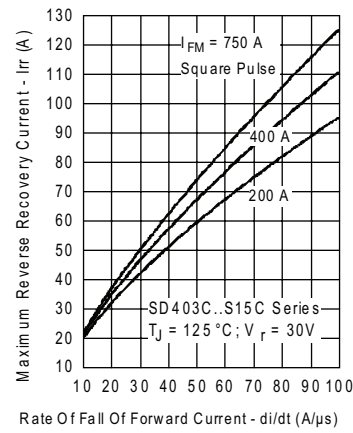


Fig. 16 - Recovery Current Characteristics

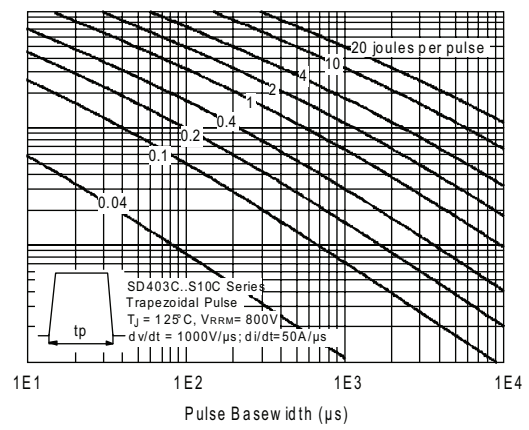
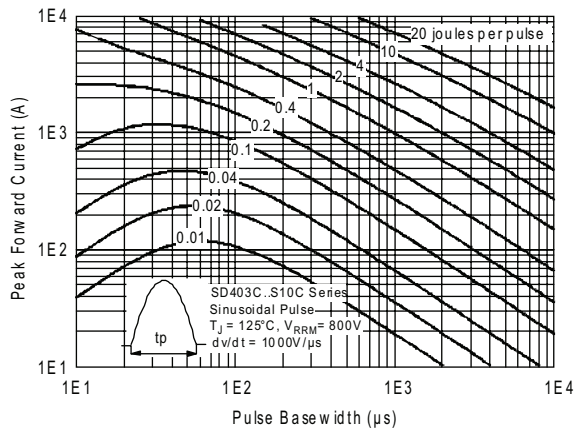


Fig. 17 - Maximum Total Energy Loss Per Pulse Characteristics

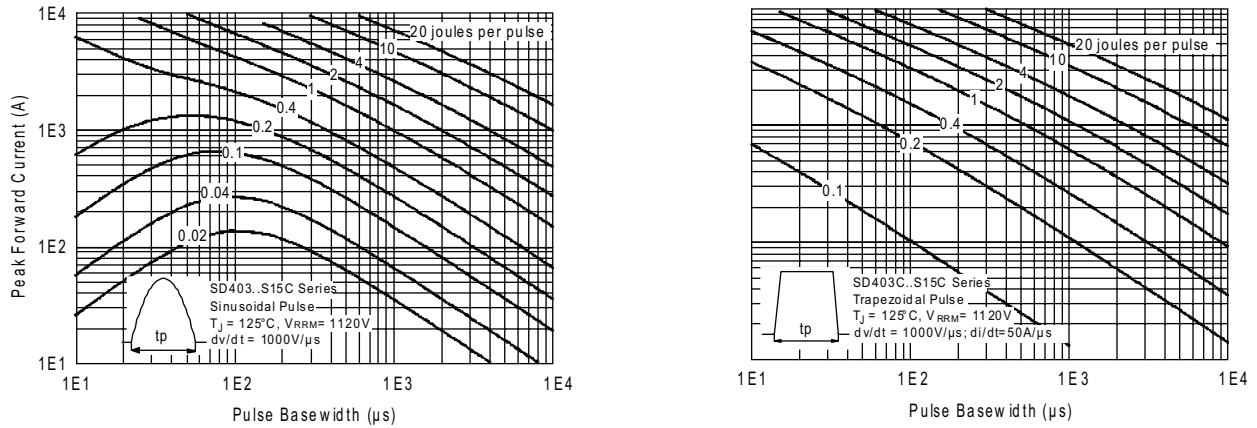


Fig. 18 - Maximum Total Energy Per Pulse Characteristics

ORDERING INFORMATION TABLE

Device code	SD	40	3	C	16	S15	C		
	①	②	③	④	⑤	⑥	⑦		
	1	-	Diode	2	-	Essential part number	3	-	3 = Fast recovery
	4	-	C = Ceramic PUK	5	-	Voltage code x 100 = V_{RRM} (see Voltage Ratings table)	6	-	t_{rr} code (see Recovery Characteristics table)
	7	-	C = PUK case DO-200AA						

LINKS TO RELATED DOCUMENTS

Dimensions	http://www.vishay.com/doc?95248
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